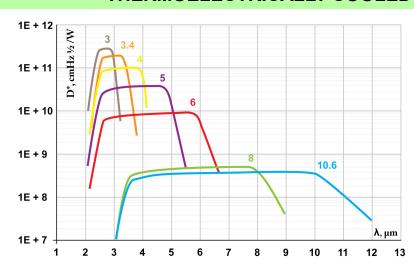
## **PV-4TE SERIES**

# 2-13 µm IR PHOTOVOLTAIC DETECTORS THERMOELECTRICALLY COOLED





#### **FEATURES**

- High performance in the 2-13 µm wavelength range
- No flicker noise
- Convenient to use
- Wide dynamic range
- Compact, rugged and reliable
- Low cost
- Prompt delivery
- Custom design upon request

#### DESCRIPTION

detector on four-stage thermoelectrical cooler. The devices are optimized for the maximum performance at  $\lambda_{\text{opt}}$ . Cut-on wavelength can be optimized upon request. Reverse bias may significantly increase speed of response and dynamic range. It results also in improved performance at high frequencies, but 1/f noise that appears in biased devices may reduce performance at low frequencies.

Highest performance and stability are achieved by application of variable gap (HgCd)Te semiconductor, optimized doping and sophisticated surface processing. Custom devices with quadrant cells, multielement arrays, different windows, lenses and optical filters are available

Standard detectors are available in TO-8 packages with BaF<sub>2</sub> windows. Other packages, windows and connectors are also available.

### SPECIFICATION

SPECIFICATION @20°C											
CHARACTERISTICS	UNITS	PV-4TE-3	PV-4TE-3.4	PV-4TE-4	PV-4TE-5	PV-4TE-6	PV-4TE-8	PV-4TE-10.6			
$\lambda_{\mathrm{opt}}$	μm	3	3.4	4	5	6	8	10,6			
Detectivity <sup>1)</sup> : @ λ <sub>peak</sub> @ λ <sub>opt</sub>	cmHz <sup>1/2</sup> / W	≥3×10 <sup>11</sup> ≥1.5×10 <sup>11</sup>	≥2×10 <sup>11</sup> ≥1×10 <sup>11</sup>	≥1×10 <sup>11</sup> ≥6×10 <sup>10</sup>	≥4×10 <sup>10</sup> ≥1.5×10 <sup>10</sup>	≥9×10 <sup>9</sup> ≥5×10 <sup>9</sup>	≥5×10 <sup>8</sup> ≥4×10 <sup>8</sup>	≥4×10 <sup>8</sup> ≥2×10 <sup>8</sup>			
Responsivity @ λ <sub>opt</sub>	A/W	≥0.5	≥0.8	≥1	≥1.3	≥1.5	≥1.5	≥0.7			
Time constant	ns	≤20	≤20	≤20	≤20	≤15	≤8	≤6			
Resistance-optical area product	Ω×cm²	≥300	≥20	≥8	≥0.4	≥0.03	≥0.0006	≥0.0005			
Operating temperature	K	~195									
Acceptance angle, F/#	deg, -	70, 0.87									

Data sheet states minimum guaranteed D\* values for each detector model. Higher performance detectors can be provided upon request. Faster response may be achieved with high-frequency-optimized devices.

Туре	Length or diameter [mm]										
	0.025	0.05	0.1	0.2	0.25	0.5	1	2	3	4	
PV-4TE-3	0	X	X	0		0	0				
PV-4TE-3.4	0	X	X	0		0	0				
PV-4TE-4	0	Х	Х	0		0	0				
PV-4TE-5	0	X	X	0		0	0				
PV-4TE-6	0	Х	Х	0		0	0				
PV-4TE-8	Х	X <sup>1)</sup>	Р								
PV-4TE-10.6	Х	X <sup>1)</sup>	Р								

<sup>&</sup>lt;sup>(1)</sup>Custom detector may require reverse bias in order to increase dynamic resistance and improve frequency response.

<sup>-</sup> detectors available on request, parameters may differ from these in data sheets



default with reverse bias